

Features

- Trench LV MOSFET Technology
- ESD Protected Up To 2KV (HBM)
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

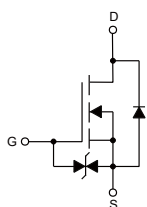
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Maximum Thermal Resistance: 425°C/W Junction to Ambient^(Note2)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±12	V
Continuous Drain Current	I_D	$T_A=25^\circ\text{C}$	0.75
		$T_A=100^\circ\text{C}$	0.47
Pulsed Drain Current ^(Note3)	I_{DM}	3	A
Total Power Dissipation ^(Note4)	P_D	0.3	W

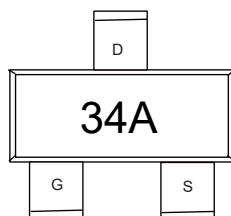
Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR-4 board with 2 oz copper, in a still air environment with $T_A=25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code

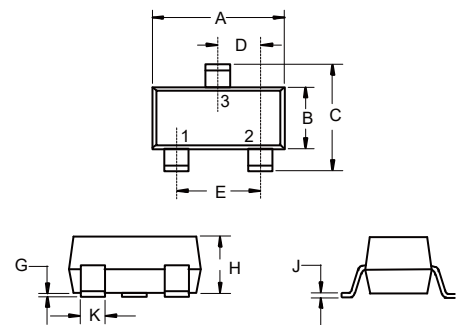


1. GATE
2. SOURCE
3. DRAIN



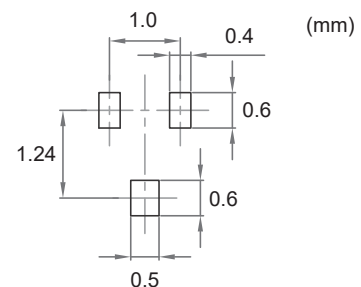
N-Channel MOSFET

SOT-523



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.059	0.067	1.50	1.70	
B	0.030	0.033	0.75	0.85	
C	0.057	0.069	1.45	1.75	
D	0.020		0.50		TYP.
E	0.035	0.043	0.90	1.10	
G	0.000	0.004	0.00	0.10	
H	0.024	0.031	0.60	0.80	
J	0.004	0.008	0.10	0.20	
K	0.006	0.014	0.15	0.35	

Suggested Solder Pad Layout



ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20			V
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	0.7	1.1	V
Gate-Body Leakage Current	I_{GSS}	$V_{GS}=\pm 10V, V_{DS}=0V$			± 10	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$			1	μA
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=500mA$		185	300	m Ω
		$V_{GS}=2.5V, I_D=400mA$		268	400	
		$V_{GS}=1.8V, I_D=200mA$		440	700	
Forward Transconductance	g_{FS}	$V_{DS}=5V, I_D=0.75A$		1.6		S
Gate Resistance	R_g	f=1 MHz, Open drain		37		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				0.75	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=500mA$			1.2	V
Reverse Recovery Time	t_{rr}	$I_F=0.5A, di_F/dt=100A/\mu s$		12		ns
Reverse Recovery Charge	Q_{rr}			0.6		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=16V, V_{GS}=0V, f=1MHz$		28		pF
Output Capacitance	C_{oss}			9.5		
Reverse Transfer Capacitance	C_{rss}			4.6		
Total Gate Charge	Q_g	$V_{DS}=10V, V_{GS}=4.5V, I_D=0.5A$		1.2		nC
Gate-Source Charge	Q_{gs}			0.26		
Gate-Drain Charge	Q_{gd}			0.23		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, V_{GS}=10V, R_G=3\Omega, I_D=0.5A$		2		ns
Turn-On Rise Time	t_r			17		
Turn-Off Delay Time	$t_{d(off)}$			14		
Turn-Off Fall Time	t_f			26		

Curve Characteristics

Fig.1 - Typical Output Characteristics

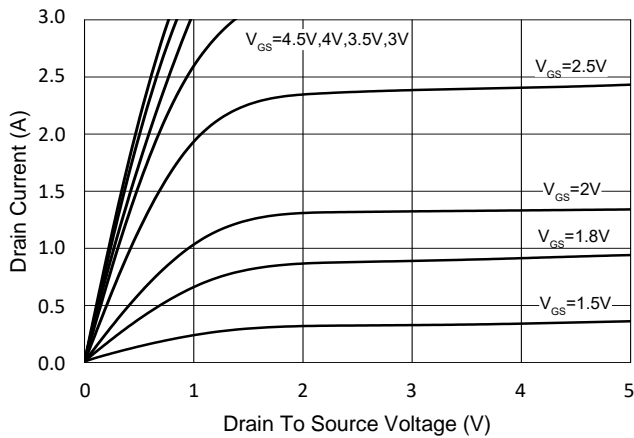


Fig.2 - Transfer Characteristic

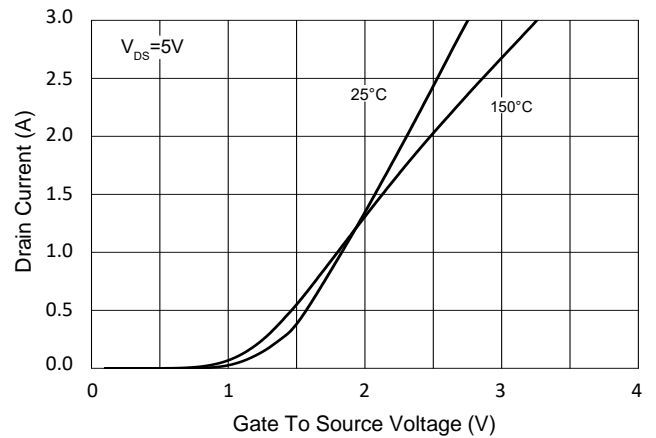


Fig.3 - $R_{DS(ON)}$ - V_{GS}

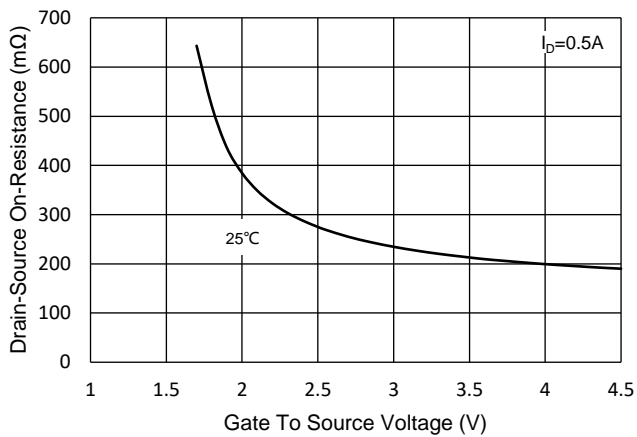


Fig.4 - $R_{DS(ON)}$ - I_D

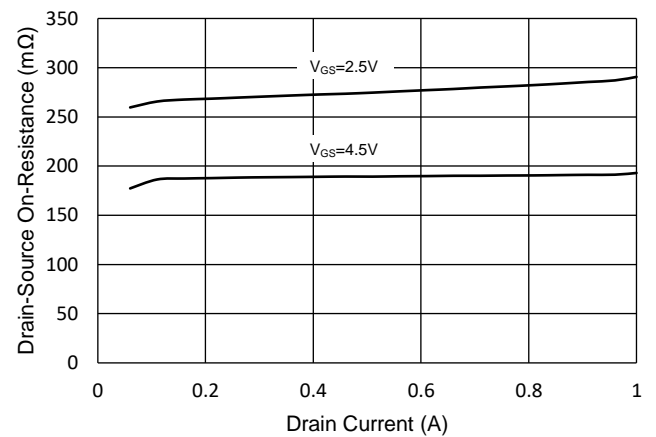


Fig.5 - Capacitance Characteristics

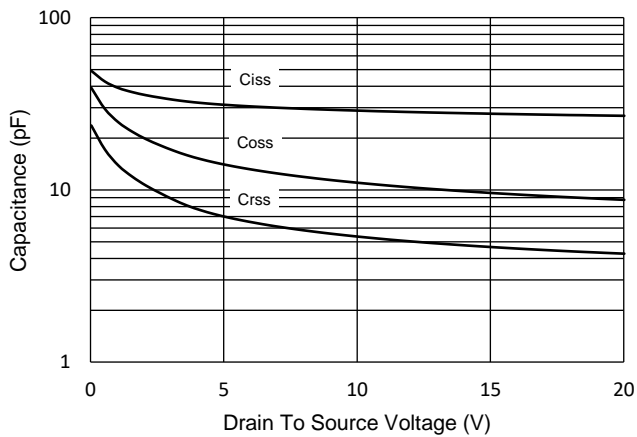
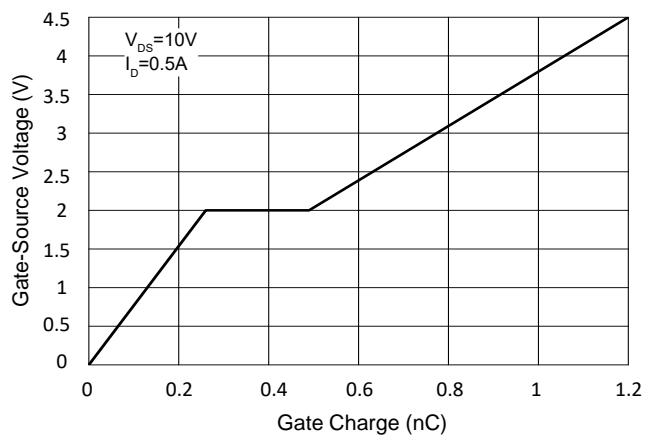


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

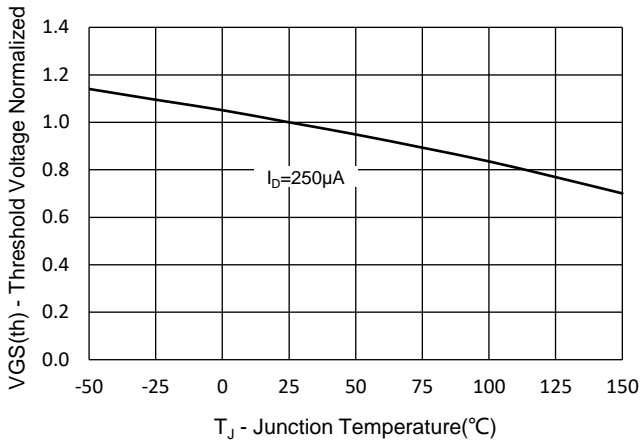


Fig.8 - Normalized On Resistance Characteristics

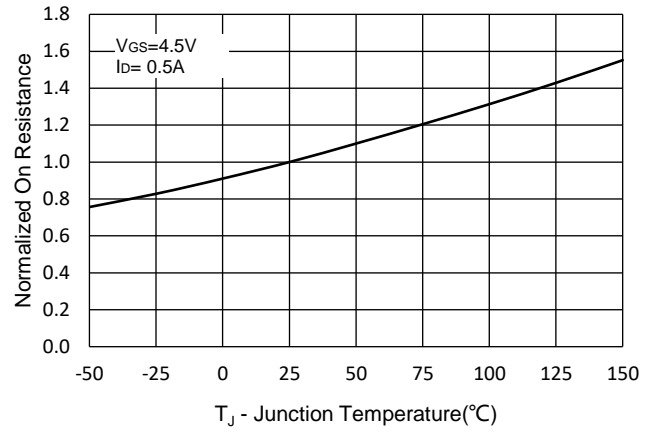


Fig.9 - I_S - V_{SD}

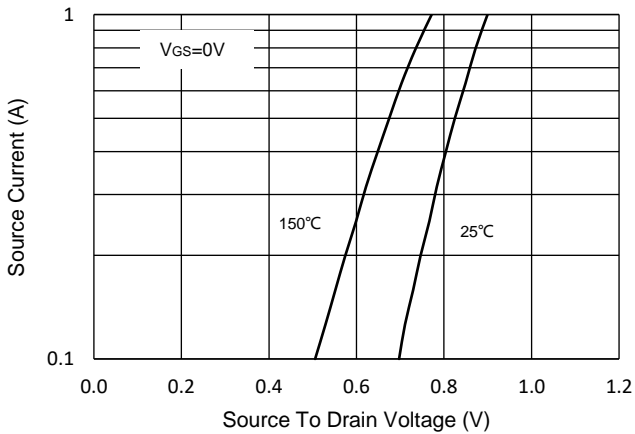


Fig.10 - Drain Current

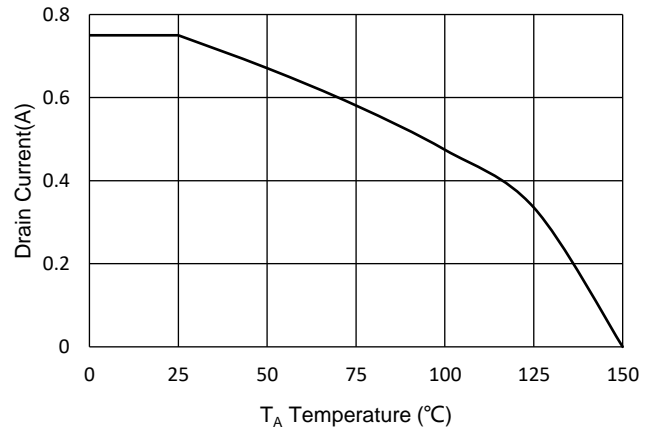
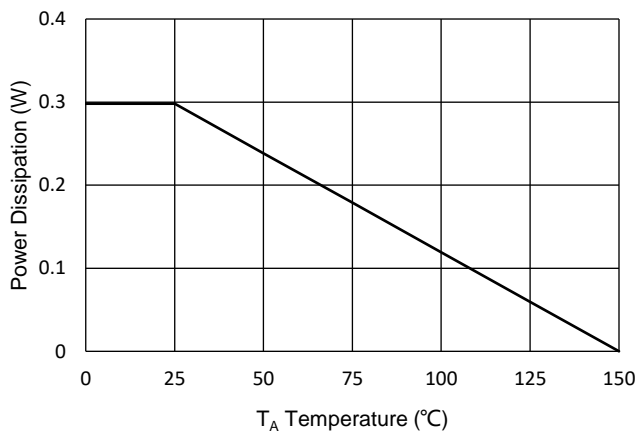


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

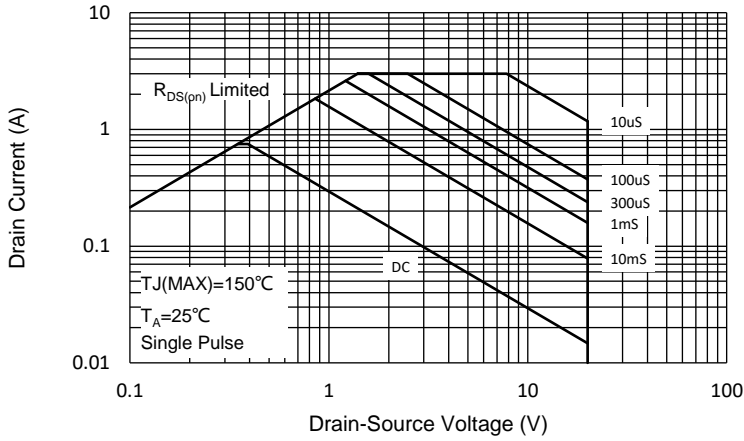
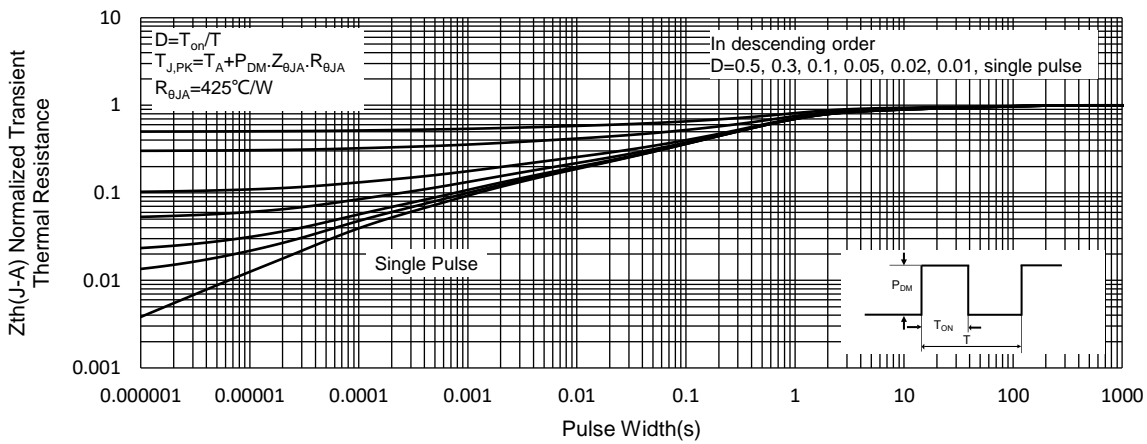


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel
Part Number-13P	Tape&Reel: 10Kpcs/Reel

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